

TECHNICAL DATA
DATA SHEET 808, REV. C

HERMETIC POWER SCHOTTKY RECTIFIER 200°C Maximum Operation Temperature

DESCRIPTION: A 150 VOLT, 15 AMP, POWER SCHOTTKY RECTIFIER IN A HERMETIC SHD-1/1B PACKAGE.

MAXIMUM RATINGS

ALL RATINGS ARE @ $T_C = 25^\circ\text{C}$ UNLESS OTHERWISE SPECIFIED.

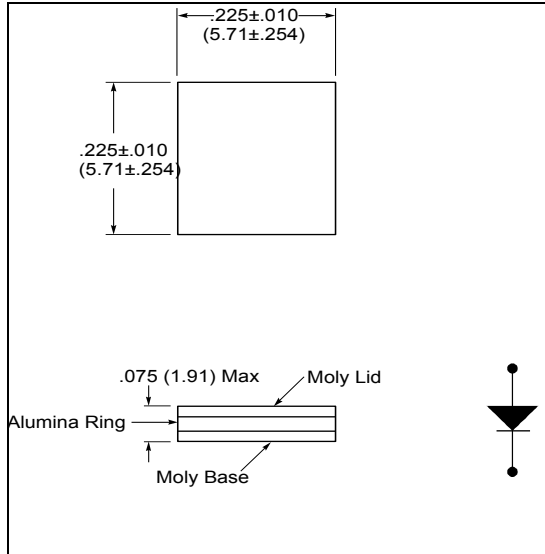
RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE	PIV	150	Volts
MAXIMUM DC OUTPUT CURRENT (With Cathode Maintained @ $T_C=100^\circ\text{C}$)	I_o	15	Amps
MAXIMUM NONREPETITIVE FORWARD SURGE CURRENT (t=8.3ms, Sine)	I_{FSM}	280	Amps
MAXIMUM JUNCTION CAPACITANCE ($V_r=5\text{V}$)	C_T	500	pF
MAXIMUM THERMAL RESISTANCE (Junction to Mounting Surface, Cathode)	$R_{\theta JC}$	1.7	$^\circ\text{C/W}$
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	Top/Tstg	-65 to + 200	$^\circ\text{C}$

ELECTRICAL CHARACTERISTICS

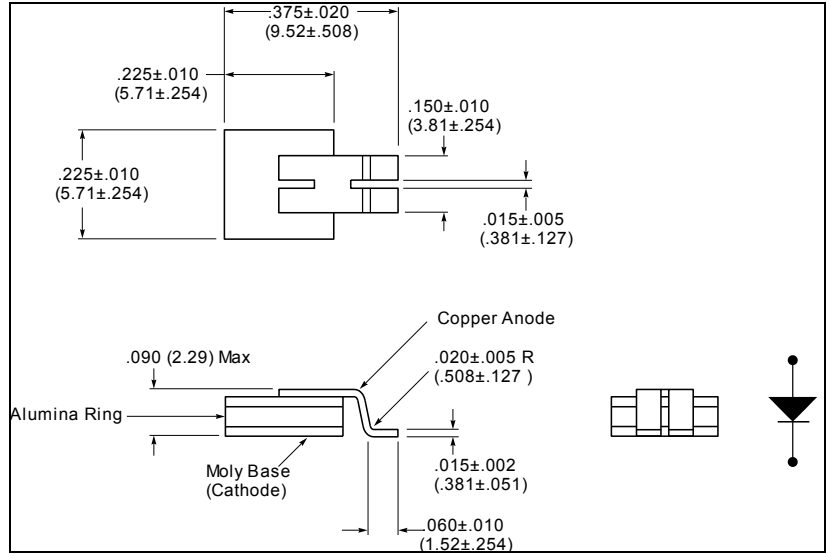
CHARACTERISTIC	SYMBOL	MAX.	UNITS
MAXIMUM FORWARD VOLTAGE DROP, Pulsed ($I_f = 15$ Amps) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	V_f	0.85 0.69	Volts
MAXIMUM REVERSE CURRENT (I_r @ 150V PIV) $T_J = 25^\circ\text{C}$ $T_J = 125^\circ\text{C}$	I_r	0.5 8.0	mA

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MECHANICAL DIMENSIONS: In Inches / mm

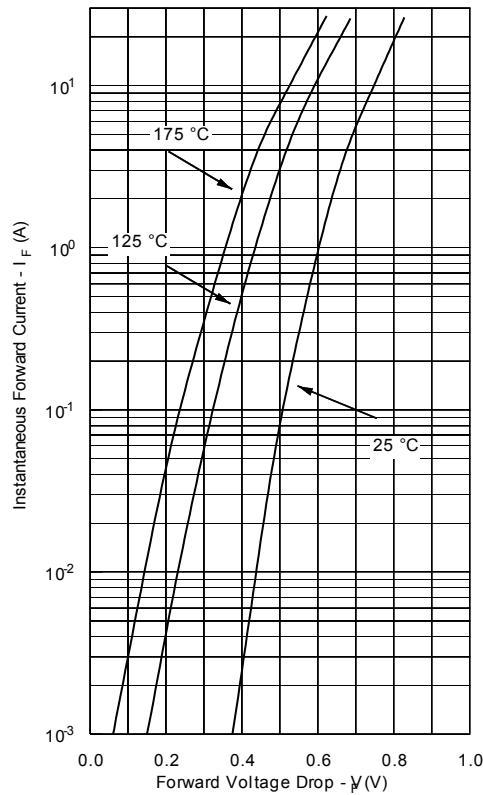


SHD-1

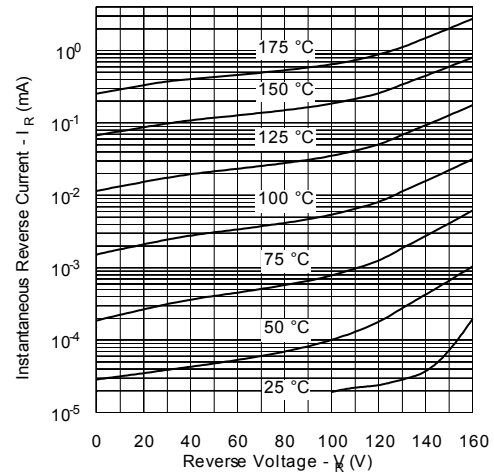


SHD-1B

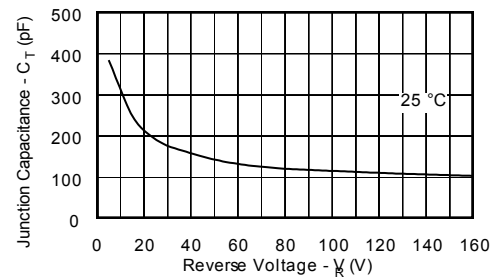
Typical Forward Characteristics



Typical Reverse Characteristics



Typical Junction Capacitance



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